

Nanoscale Optoelectronic Characterizations of Microstructured Thin-Film Solar Cells



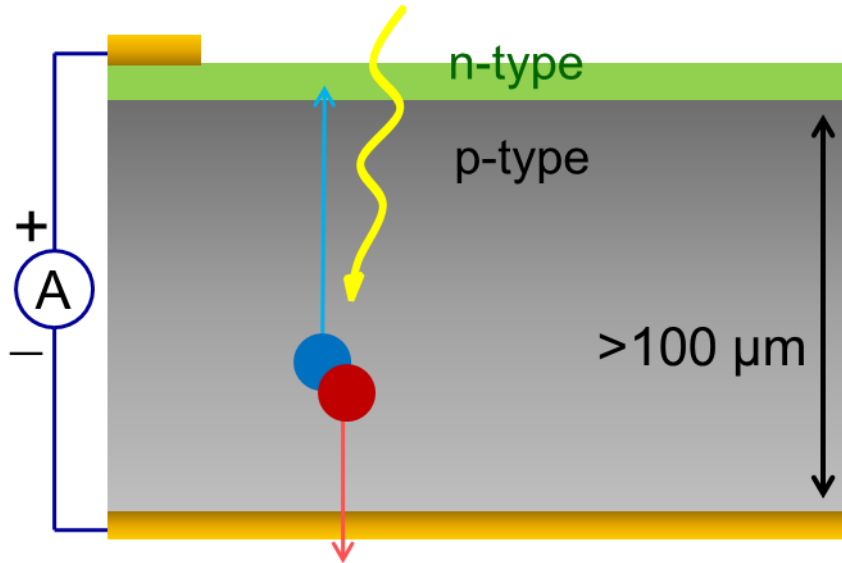
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Electrical and Computer Engineering

Materials In Space Workshop (July 22, 2018)

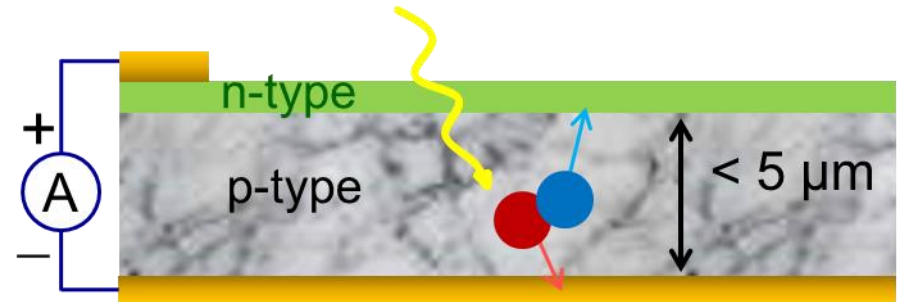


Thin film PV uses inexpensive materials.



■ c-Si solar cell

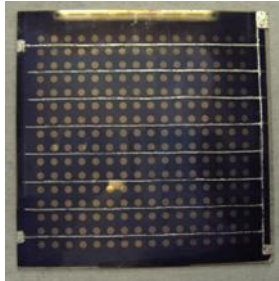
- Thick (indirect band-gap)
- High purity (large $L_{n,p}$)
- High efficiency, but expensive



■ px -CdTe, CIGS, CZTS(Se)

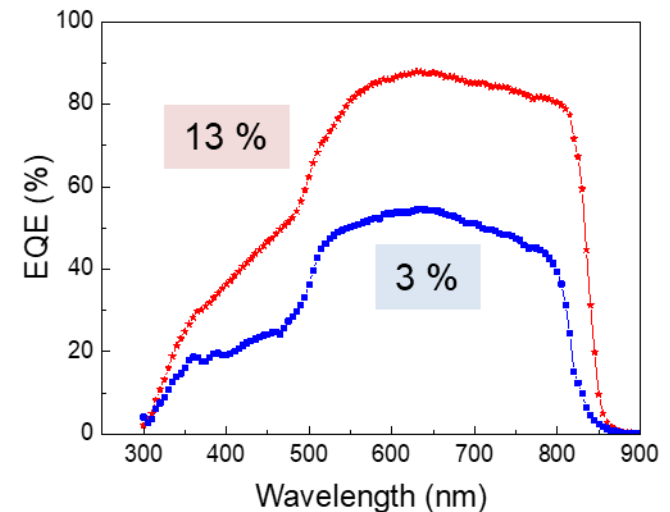
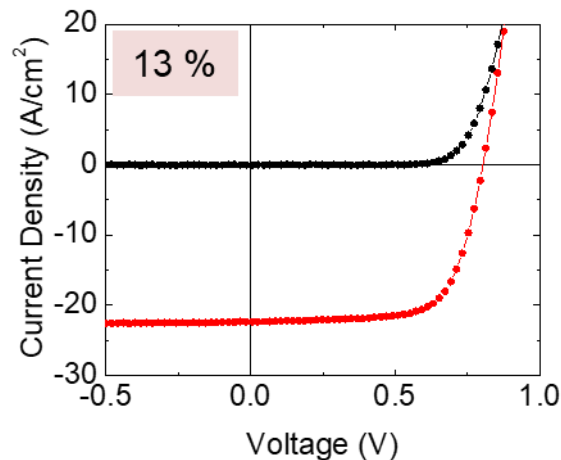
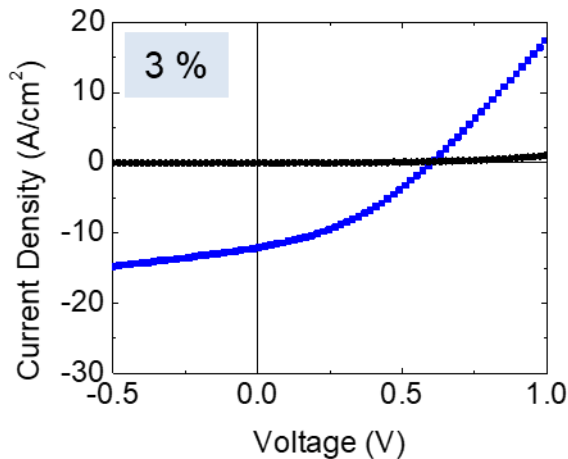
- Thin (direct band-gap)
- Highly defective (grains, GBs)
- Flexible (e.g., metal foil substrate)
- Relatively high efficiency
(\rightarrow can be improved more)

EQE (1 sun illumination) reflects J_{sc}



CdTe solar cells fabricated by magnetron sputtering system*

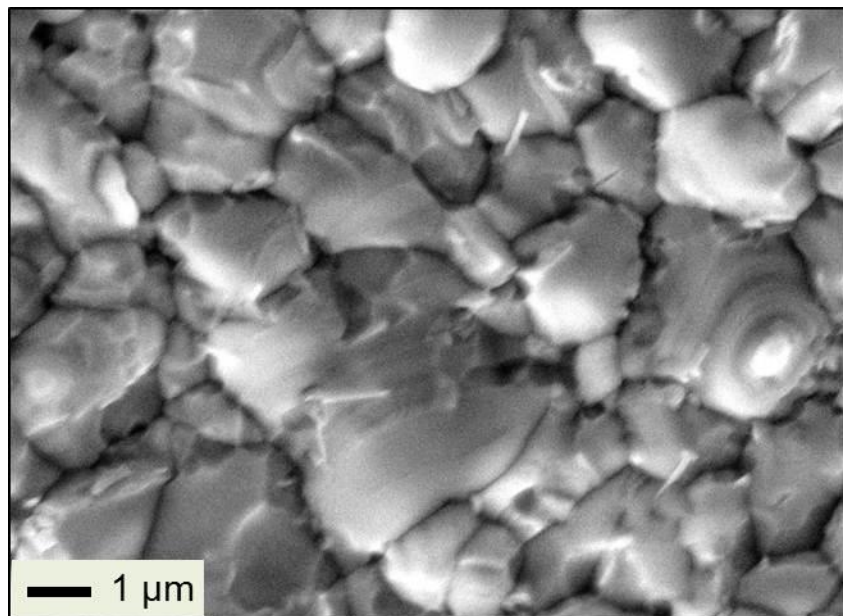
η (%)	V_{oc} (V)	J_{sc} (mA / cm ²)	FF (%)	R_s (Ω cm ²)	R_{SH} (Ω cm ²)
13.2	0.801	23.5	70	3	1650
3.0	0.605	13.0	38	20	260



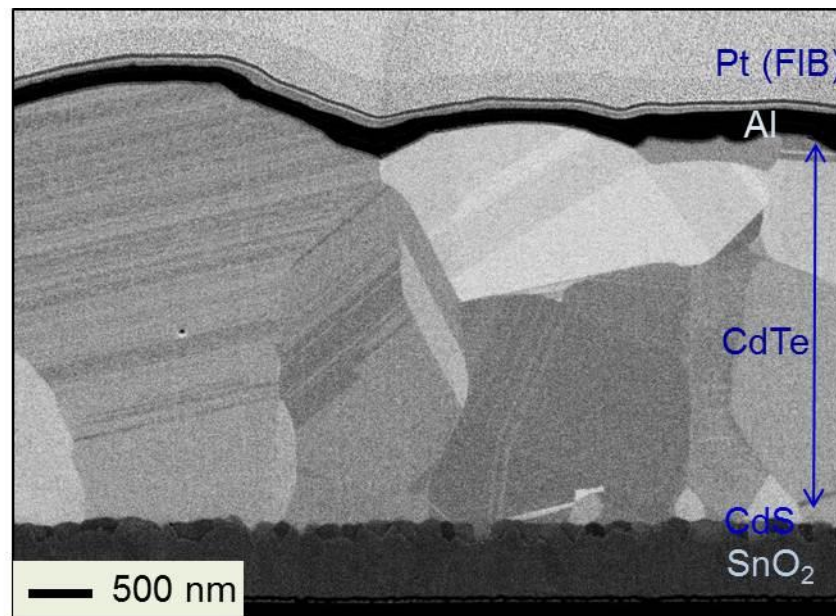
- CdTe absorber of 3 % device is highly resistive.
- EQE analysis shows carrier collection efficiency in each layer and interfaces.

The microstructure of CdTe is not homogeneous.

top view



cross section



- Comprised of grains (a few μm in size): lots of grain boundaries (GB)
 - Local variation of chemical composition, defects
 - Inhomogeneous (photo)current
- **impact of GBs on efficiency – mainly unknown**

Need for metrology to access properties of individual GB / GI (grain interior)

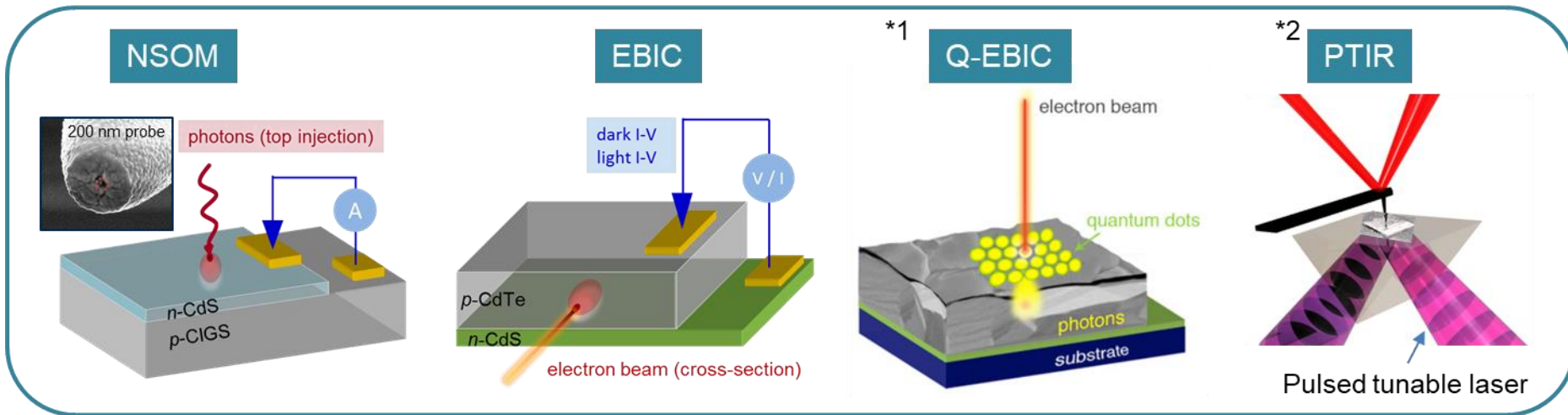
Techniques for Local PV Characterizations

✓ Local Probe

- Nanocontacts + nanoprobe
- Scanning probes
- Cathodoluminescence
- Photo-thermal induced resonance

✓ Local Excitation

- Electron beam
- Near field optical source
- Ebeam + QD \rightarrow photons (down-conversion)



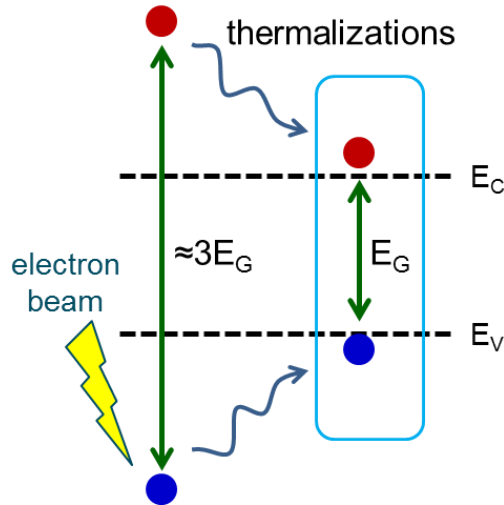
- ✓ Sample prep: plan view / cross-section / wedge / lamella / nanocontacts
- ✓ Correlation with structural / compositional properties (TEM, EDX, EBSD, XRD)
- ✓ Modelling

*1. H. Yoon *et al.*, AIP Advances (6), 062112, 9 439 (2013)

*2. B. Lahiri *et al.*, Small, 9 439 (2013); Y. Yoon *et al.*, Nanoscale, 9, 7771-7780 (2017)

Electron beams generate EHPs → EBIC

(1) $I_{\text{beam}} \rightarrow$ generation rate of EHP

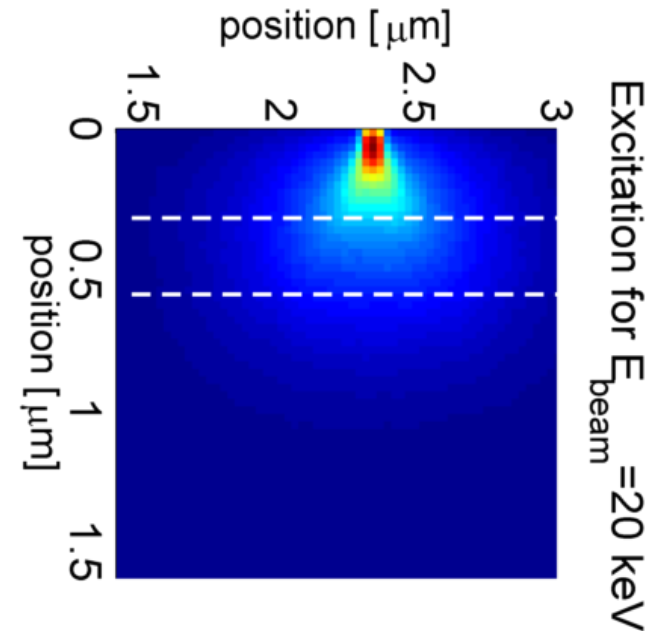


$$(\# \text{ of EHPs}) \approx \frac{(\text{deposited e-beam energy})}{3 \times (\text{energy band-gap})}$$

e.g. CdTe: $E_G = 1.5 \text{ eV}$, $V_{\text{beam}} = 10 \text{ keV}$ (BSE $\approx 30 \%$)

$\Rightarrow \approx 1600 \text{ ehp}$

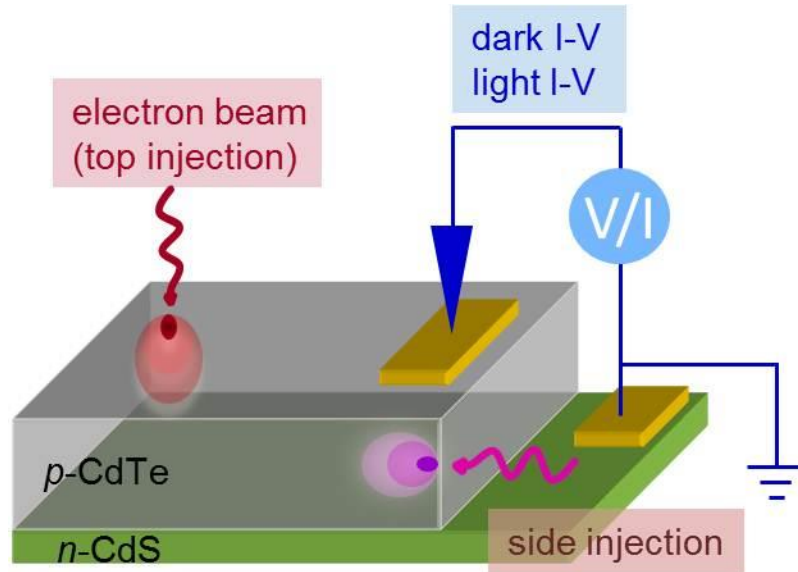
(2) $V_{\text{beam}} \rightarrow$ generation bulb size



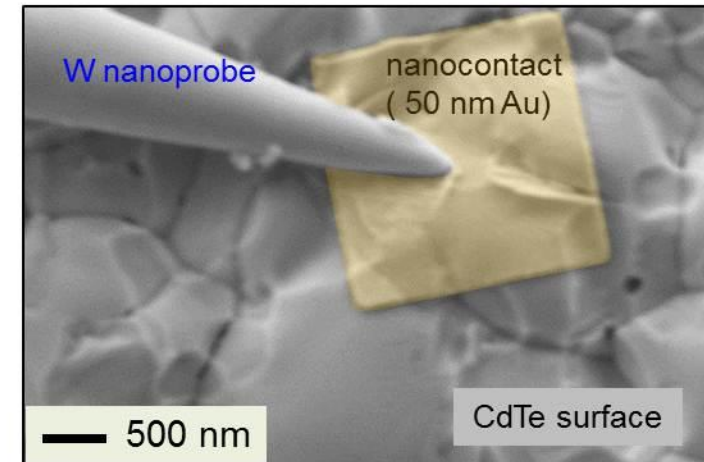
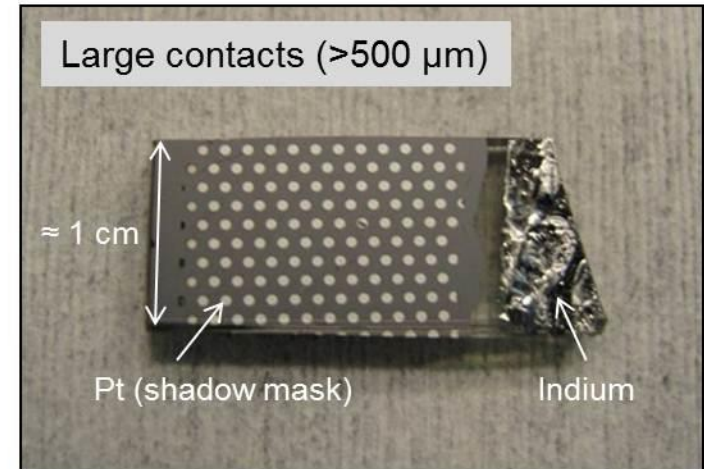
EBIC: Electron Beam Induced Current

EBIC is an ideal technique for systematic study of local carrier dynamics.

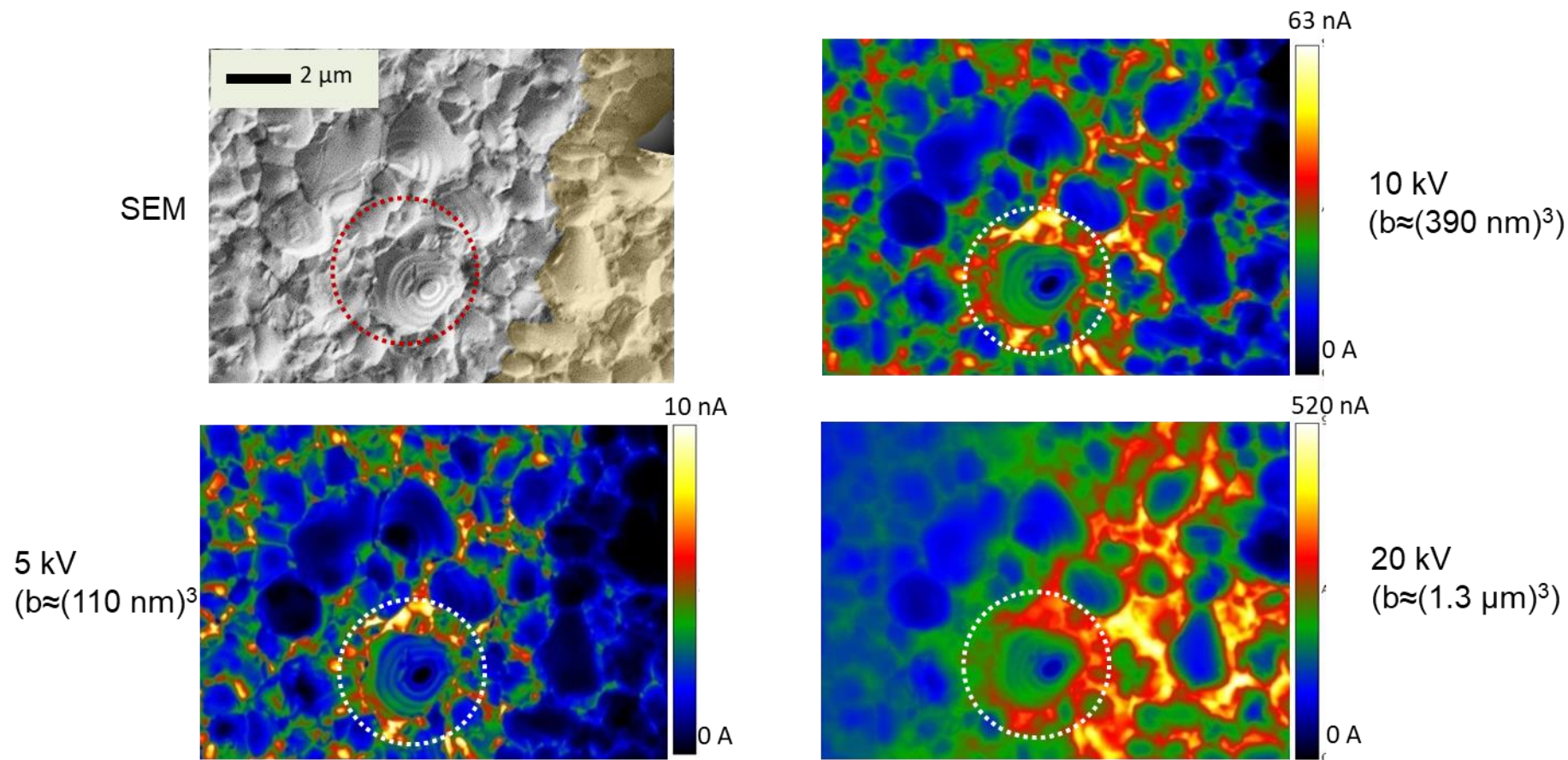
EBIC for Grain / Grain Boundary Characterizations



- Injection: top surface, cross-section, wedge
- Local carrier generation
(bulb size: 110 nm to 1.5 μm in CdTe)
- Nano-contacts at grain boundary / grain bulk
- **Probe PV properties of individual grains**

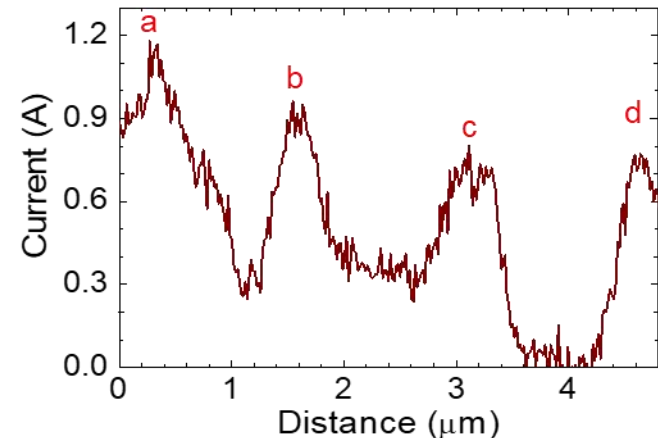
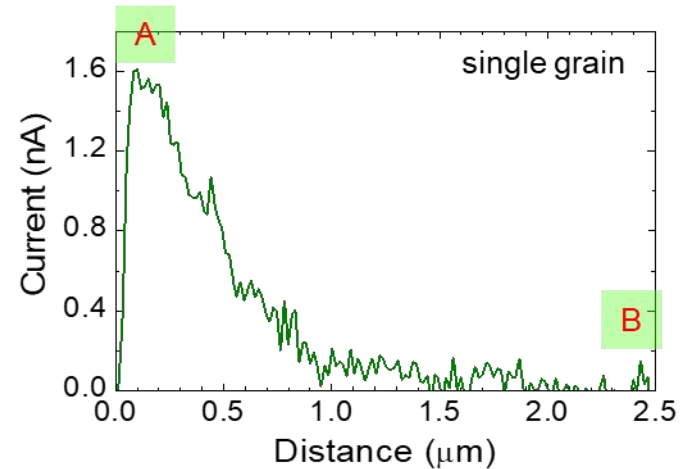
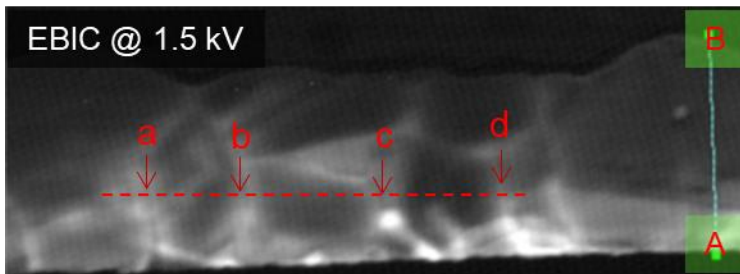
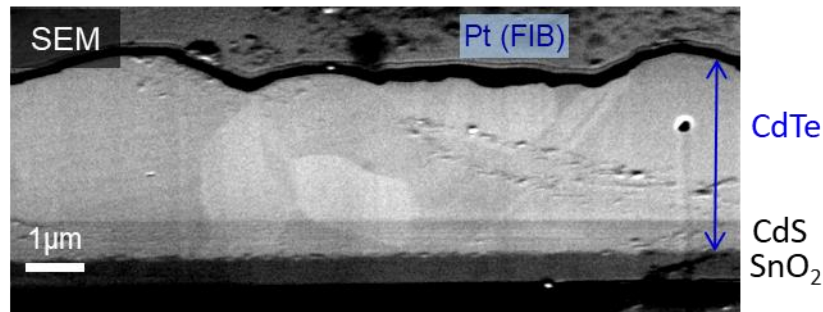
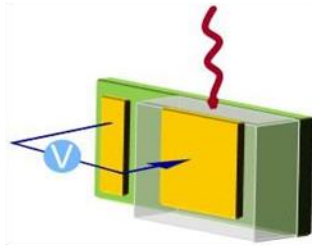


Spatial resolution < 100 nm with low keV



- High keV increases signal-to-noise ratio, but lower the spatial resolution.
- Higher collection at grain boundaries

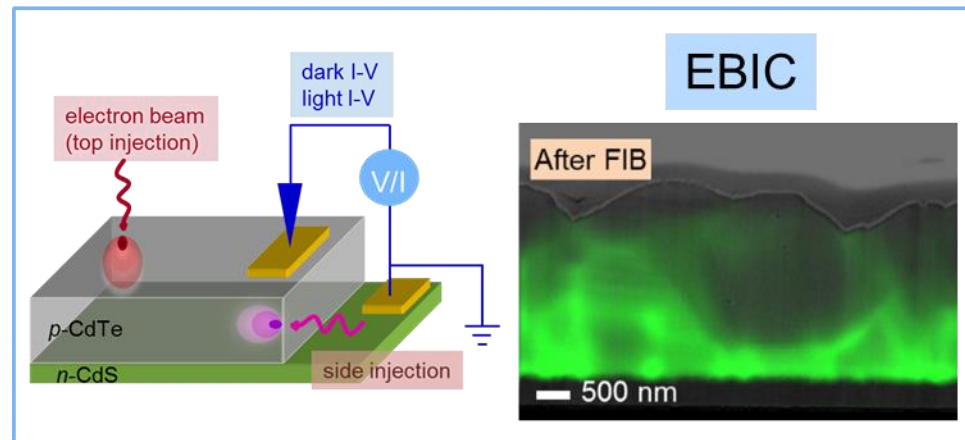
Carriers are collected efficiently at GBs in CdTe.



- Smooth surface was prepared by FIB.
- Grain boundaries in CdTe collect carriers more effectively than grain interiors.

Summary

- ✓ Physics of thin film PV is important and exciting.
- ✓ **EBIC allows qualitative AND quantitative characterization of PV materials**
 - Deconvolution of EBIC signal provides material parameters
 - Surface effects in EBIC are strong at the depletion region (and GB?)
- ✓ In progress: correlating local properties to overall device performance (electrical, optical, chemical, structural properties)



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Research participants / collaborators

- CdTe solar cell (U. Toledo)
- CIGS solar cell (U. Toledo)
- CZTS solar cell (DuPont)
- Si solar cells: epi Si, high-efficiency PV (NREL)

Thank you for your attention!